

## Small Signal Switching Diode

### Features

- Silicon Epitaxial Planar Diode
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



94 9367

### Applications

- Extreme fast switches

### Mechanical Data

**Case:** DO35 Glass case

**Weight:** approx. 125 mg

**Cathode Band Color:** black

**Packaging Codes/Options:**

TR/10 k per 13" reel (52 mm tape), 50 k/box

TAP/10 k per Ammpack (52 mm tape), 50 k/box

### Parts Table

| Part  | Ordering code         | Type Marking | Remarks               |
|-------|-----------------------|--------------|-----------------------|
| BAW75 | BAW75-TR or BAW75-TAP | BAW75        | Tape and Reel/Ammpack |

### Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

| Parameter                       | Test condition                                         | Symbol    | Value | Unit |
|---------------------------------|--------------------------------------------------------|-----------|-------|------|
| Repetitive peak reverse voltage |                                                        | $V_{RRM}$ | 35    | V    |
| Reverse voltage                 |                                                        | $V_R$     | 25    | V    |
| Peak forward surge current      | $t_p = 1\text{ }\mu\text{s}$                           | $I_{FSM}$ | 2000  | mA   |
| Repetitive peak forward current |                                                        | $I_{FRM}$ | 450   | mA   |
| Forward continuous current      |                                                        | $I_F$     | 300   | mA   |
| Average forward current         | $V_R = 0$                                              | $I_{FAV}$ | 150   | mA   |
| Power dissipation               | $l = 4\text{ mm}, T_L = 45\text{ }^{\circ}\text{C}$    | $P_{tot}$ | 440   | mW   |
|                                 | $l = 4\text{ mm}, T_L \leq 25\text{ }^{\circ}\text{C}$ | $P_{tot}$ | 500   | mW   |

### Thermal Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

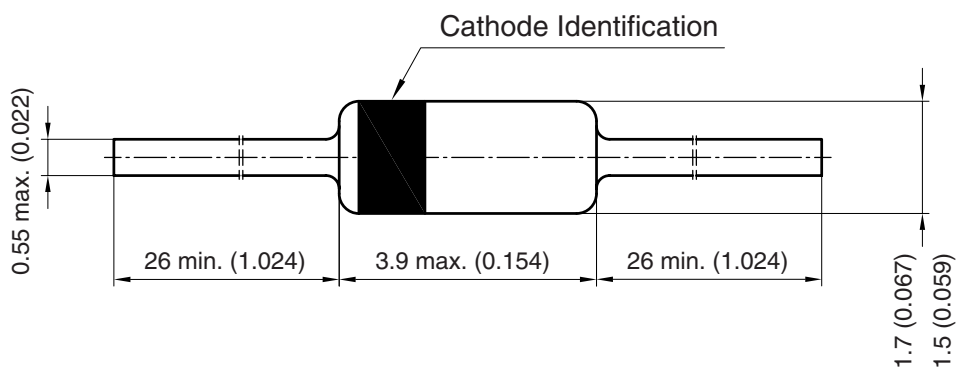
| Parameter                                  | Test condition                           | Symbol     | Value         | Unit               |
|--------------------------------------------|------------------------------------------|------------|---------------|--------------------|
| Thermal resistance junction to ambient air | $l = 4\text{ mm}, T_L = \text{constant}$ | $R_{thJA}$ | 350           | K/W                |
| Junction temperature                       |                                          | $T_j$      | 175           | $^{\circ}\text{C}$ |
| Storage temperature range                  |                                          | $T_{stg}$  | - 65 to + 175 | $^{\circ}\text{C}$ |

## Electrical Characteristics

T<sub>amb</sub> = 25 °C, unless otherwise specified

| Parameter             | Test condition                                                                              | Symbol            | Min | Typ. | Max  | Unit |
|-----------------------|---------------------------------------------------------------------------------------------|-------------------|-----|------|------|------|
| Forward voltage       | I <sub>F</sub> = 30 mA                                                                      | V <sub>F</sub>    |     |      | 1000 | mV   |
| Reverse current       | V <sub>R</sub> = 25 V                                                                       | I <sub>R</sub>    |     |      | 100  | nA   |
|                       | V <sub>R</sub> = 25 V, T <sub>j</sub> = 150 °C                                              | I <sub>R</sub>    |     |      | 100  | μA   |
| Breakdown voltage     | I <sub>R</sub> = 5 μA, t <sub>p</sub> /T = 0.01, t <sub>p</sub> = 0.3 ms                    | V <sub>(BR)</sub> | 35  |      |      | V    |
| Diode capacitance     | V <sub>R</sub> = 0, f = 1 MHz, V <sub>HF</sub> = 50 mV                                      | C <sub>D</sub>    |     |      | 4    | pF   |
| Reverse recovery time | I <sub>F</sub> = I <sub>R</sub> = 10 mA, I <sub>R</sub> = 1 mA                              | t <sub>rr</sub>   |     |      | 4    | ns   |
|                       | I <sub>F</sub> = 10 mA, V <sub>R</sub> = 6 V, I <sub>R</sub> = 1 mA, R <sub>L</sub> = 100 Ω | t <sub>rr</sub>   |     |      | 2    | ns   |

## Package Dimensions in millimeters (inches): DO35



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## Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

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Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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## JONHON

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Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: [ocean@oceanchips.ru](mailto:ocean@oceanchips.ru)

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А